



A Product Line of Diodes Incorporated



ZXTN2005G

25V NPN LOW SATURATION TRANSISTOR IN SOT223

Features

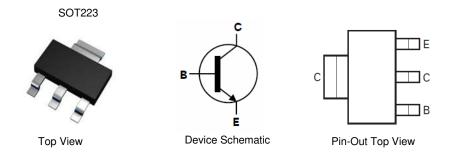
- $BV_{CEO} > 60V$
- I_C = 7A Continuous Collector Current
- I_{CM} = 20A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < 50mV max @ 1A
- R_{SAT} = 30mΩ @ 6.5A for Low Equivalent On-Resistance
- hFE Specified up to 20A for High Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

Applications

- **DC-DC Converters**
- **MOSFET Gate Drivers**
- **Charging Circuits**
- **Power Switches**
- Motor Control



Ordering Information (Note 4)

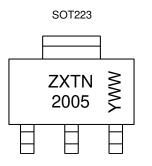
Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel	
ZXTN2005GTA	ZXTN2005	7	12	1,000	
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.					

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

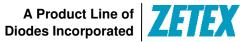
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ZXTN 2005 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W = Week Code (01~53)$





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	25	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	7	А
Peak Pulse Current	I _{CM}	20	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

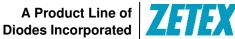
Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	5	3.0 24	W mW/°C	
Linear Derating Factor	(Note 6)	PD	1.6 12.8		
Thermal Desistance, Junction to Ambient	(Note 5)	R _{0JA}	42		
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	78	°C/W	
Thermal Resistance, Junction to Lead (Note 7		R _{θJL}	8.8		
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

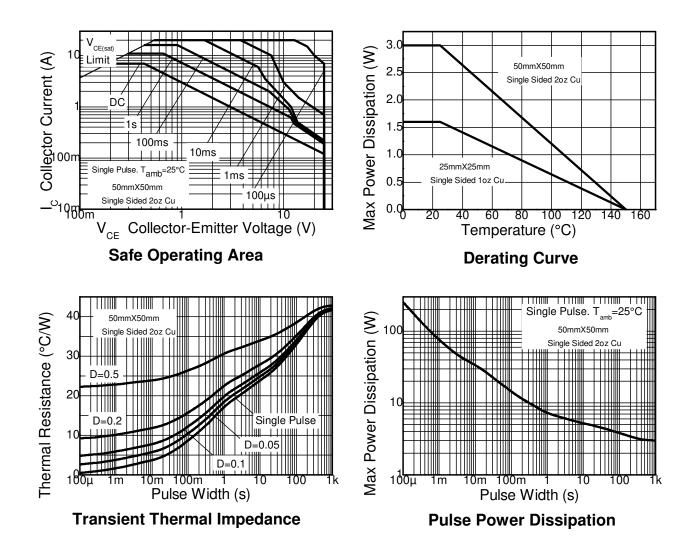
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air Notes: To a device mounted with the collector lead on 25mm x 52mm 202 copper that is conditions whilst operating in steady-state.
Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating Information







Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		60	120	—	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage		60	120	—	V	I _C = 1μA, RB ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	25	35	—	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	7.0	8.1	_	V	I _E = 100μA
Collector Cut-Off Current	I _{CBO}	_	< 1 —	50 0.5	nA μA	$V_{CB} = 50V$ $V_{CB} = 50V, T_{A} = +100^{\circ}C$
Collector Cut-Off Current	l _{CER} R≤1kΩ	_	< 1 —	100 0.5	nA μA	$V_{CB} = 50V$ $V_{CB} = 50V, T_A = +100^{\circ}C$
Emitter Cut-Off Current	I _{EBO}	—	< 1	10	nA	$V_{EB} = 6V$
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	_	28 35 55 115 195	40 50 75 140 230	mV	$\begin{split} I_{C} &= 500 \text{mA}, \ I_{B} &= 10 \text{mA} \\ I_{C} &= 1 \text{A}, \ I_{B} &= 100 \text{mA} \\ I_{C} &= 1 \text{A}, \ I_{B} &= 10 \text{mA} \\ I_{C} &= 2 \text{A}, \ I_{B} &= 10 \text{mA} \\ I_{C} &= 6.5 \text{A}, \ I_{B} &= 150 \text{mA} \end{split}$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	980	1080	mV	$I_C = 6.5A, I_B = 150mA$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	—	890	980	mV	$I_{C} = 6.5A, V_{CE} = 1V$
DC Current Gain (Note 9)	h _{FE}	300 300 200 40	400 450 275 55	_	_	$ I_C = 10 mA, V_{CE} = 1V \\ I_C = 1A, V_{CE} = 1V \\ I_C = 7A, V_{CE} = 1V \\ I_C = 20A, V_{CE} = 1V $
Transition Frequency	fT	—	150	—	MHz	$V_{CE} = 10V$, $I_C = 100mA$, f = 50MHz
Output Capacitance (Note 9)	Cobo	—	48	—	pF	V _{CB} = 10V, f = 1MHz
Switching Times	t _{ON}	—	33	—	ns	$V_{CC} = 10V, I_C = 1A,$
	toff	—	464	—		$I_{B1} = -I_{B2} = 100 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

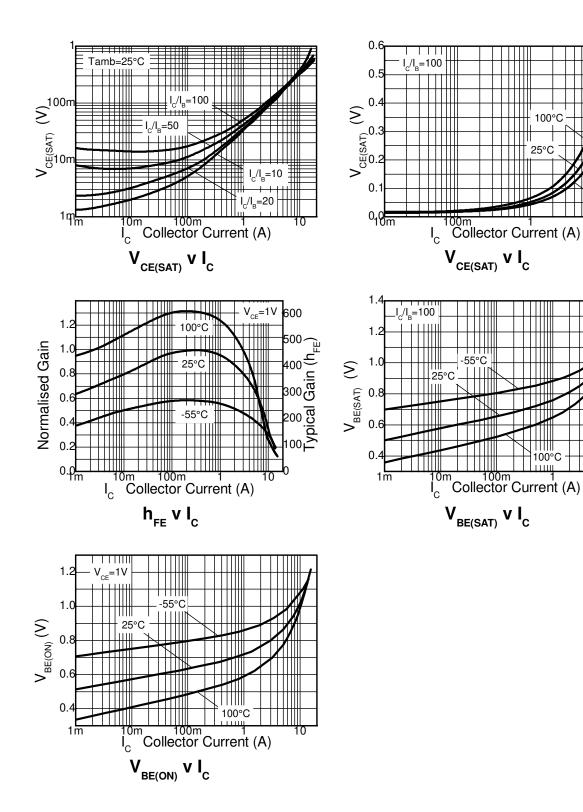


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Typical Electrical Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

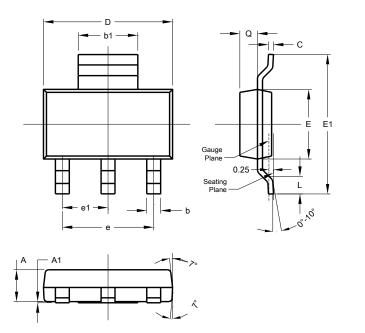






Package Outline Dimensions

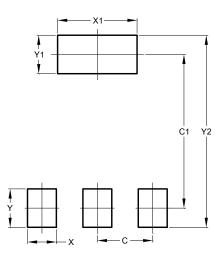
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
ш	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
e	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
C2	8.00



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